TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC109AP,TC74HC109AF,TC74HC109AFN

Dual J-K Flip-Flop with Preset and Clear

The TC74HC109A is a high speed CMOS J- \overline{K} FLIP FLOP fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

In accordance with the logic levels applied to the J and K inputs, the outputs change state on the positive going transition of the clock pulse.

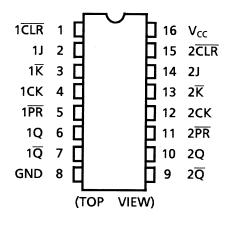
 $\overline{\text{CLR}}$ and $\overline{\text{PR}}$ are independent of the clock and are accomplished by a low logic level on the corresponding input.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

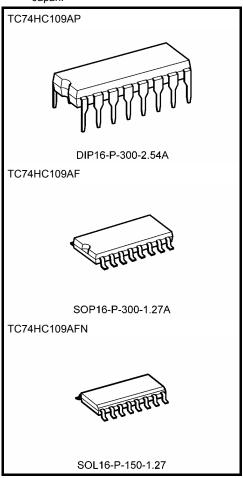
Features

- High speed: $f_{max} = 63 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: I_{CC} = 2 μA (max) at Ta = 25°C
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: | I_{OH} | = I_{OL} = 4 mA (min)
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: VCC (opr) = 2~6 V
- Pin and function compatible with 74LS109

Pin Assignment



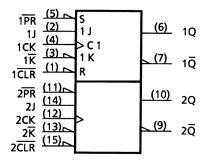
Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

DIP16-P-300-2.54A : 1.00 g (typ.) SOP16-P-300-1.27A : 0.18 g (typ.) SOL16-P-150-1.27 : 0.13 g (typ.)

IEC Logic Symbol

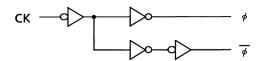


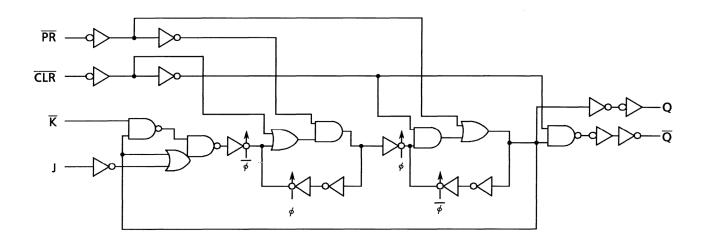
Truth Table

	Inputs				Out	puts	Function	
CLR	PR	J	ĸ	CK	Q	IQ	Function	
L	Н	Х	Х	Х	L	Н	Clear	
Н	L	Х	Х	Х	Н	L	Preset	
L	L	Х	Х	Х	Н	Н		
Н	Н	L	Н		Qn	\overline{Q}_n	No Change	
Н	Η	Ш	_		_	Η		
Н	Η	Η	Н		Η	Ш		
Н	Н	Н	L		\overline{Q}_n	Qn	Toggle	
Н	Н	Х	Х	\Box	Qn	\overline{Q}_n	No Change	

X: Don't care

System Diagram







Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7	V
DC input voltage	V _{IN}	-0.5~V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	V
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of $Ta = -40^{\circ}C \sim 65^{\circ}C$. From $Ta = 65^{\circ}C$ to $85^{\circ}C$ a derating factor of -10 mW/°C shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2~6	V
Input voltage	V _{IN}	0~V _{CC}	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
		0~1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0~500 (V _{CC} = 4.5 V)	ns
		0~400 (V _{CC} = 6.0 V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

		Test Condition			Ta = 25°C			Ta = -40~85°C			
Characteristics	Symbol				Min	Тур.	Max	Min	Max	Unit	
				2.0	1.50	_	_	1.50	_		
High-level input voltage	V _{IH}		_	4.5	3.15	_	_	3.15	_	V	
ŭ				6.0	4.20		_	4.20	_		
				2.0	_	_	0.50	_	0.50		
Low-level input voltage	V _{IL}	_		4.5	_		1.35	_	1.35	V	
ŭ				6.0			1.80		1.80		
	V _{ОН}	V _{IN} = V _{IH} or V _{IL}		2.0	1.9	2.0	_	1.9	_		
			I _{OH} = -20 μA	4.5	4.4	4.5	_	4.4	_		
High-level output voltage				6.0	5.9	6.0	_	5.9	_	V	
			I _{OH} = -4 mA	4.5	4.18	4.31	_	4.13	_		
			$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80	_	5.63	_		
		V _{IN} = V _{IH} or		2.0	_	0.0	0.1	_	0.1		
			$I_{OL} = 20 \mu A$	4.5	_	0.0	0.1	_	0.1		
Low-level output voltage	V _{OL}			6.0	_	0.0	0.1	_	0.1	V	
Ü		V _{IL}	I _{OL} = 4 mA	4.5	_	0.17	0.26	_	0.33		
			I _{OL} = 5.2 mA	6.0	_	0.18	0.26	_	0.33		
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0	_	_	±0.1	_	±1.0	μА	
Quiescent supply current	Icc	$V_{IN} = V_{C}$	V _{IN} = V _{CC} or GND		_	_	2.0	_	20.0	μА	



Timing Requirements (input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	Test Condition			Ta = -40 ~85°C	Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	*		2.0	_	75	95	
(CK)	t _{W (L)}	_	4.5	_	15	19	ns
(CK)	t _{W (H)}		6.0	_	13	16	
Minimum nula a width			2.0	_	75	95	
Minimum pulse width (PR, CLR)	t _{W (L)}	_	4.5	_	15	19	ns
(PK, GLK)			6.0	_	13	16	
			2.0	_	75	95	
Minimum set-up time	ts	_	4.5	_	15	19	ns
			6.0	_	13	16	
			2.0		0	0	
Minimum hold time	t _h	_	4.5	_	0	0	ns
			6.0	_	0	0	
Minimum removal time			2.0		50	65	
(PR, CLR)	t _{rem}	_	4.5	_	10	13	ns
(FR, OLR)			6.0	_	9	11	
			2.0	_	6	5	
Clock frequency	f	_	4.5	_	31	25	MHz
			6.0	_	36	29	

AC Characteristics (C $_L$ = 15 pF, V_{CC} = 5 V, Ta = 25 $^{\circ}\text{C},$ input: t_r = t_f = 6 ns)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t _{TLH} t _{THL}	_	_	6	12	ns
Propagation delay time (CK-Q, \overline{Q})	t _{pLH}	_	_	13	26	ns
Propagation delay time $(\overline{PR}, \overline{CLR}-Q, \overline{Q})$	t _{pLH}	_	_	13	26	ns
Maximum clock frequency	f _{max}	_	33	63	_	MHz



AC Characteristics ($C_L = 50$ pF, input: $t_r = t_f = 6$ ns)

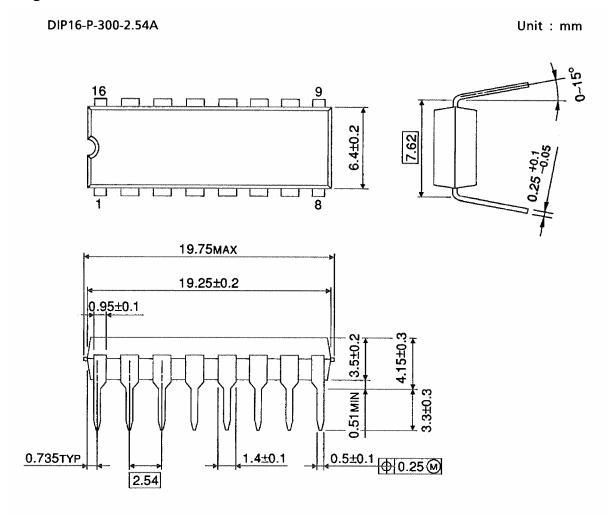
		Test Condition		Ta = 25°C		Ta = -40~85°C				
Characteristics	Symbol		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit	
	4 —		2.0	_	30	75	_	95		
Output transition time	t _{TLH}	_	4.5	_	8	15	_	19	ns	
	t _{THL}		6.0	_	7	13	_	16		
Propagation delay	4		2.0	_	50	150	_	190		
time	t _{pLH}	_	4.5	_	16	30	_	38	ns	
$(CK-Q, \overline{Q})$	t _{pHL}	₹pHL		6.0	_	13	26	_	32	
Propagation delay	4		2.0	_	50	150	_	190		
time	t _{pLH}	_	4.5	_	16	30	_	38	ns	
$(\overline{PR}, \overline{CLR}-Q, \overline{Q})$	t _{pHL}		6.0	_	13	26	_	32		
			2.0	6	17	_	5	_		
Maximum clock frequency	f _{max}	_	4.5	31	59	_	25	_	MHz	
			6.0	36	67	_	29	_		
Input capacitance	C _{IN}	_		_	5	10	_	10	pF	
Power dissipation capacitance	C _{PD} (Note)	_		_	41	_	_	_	pF	

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$ (per F/F)

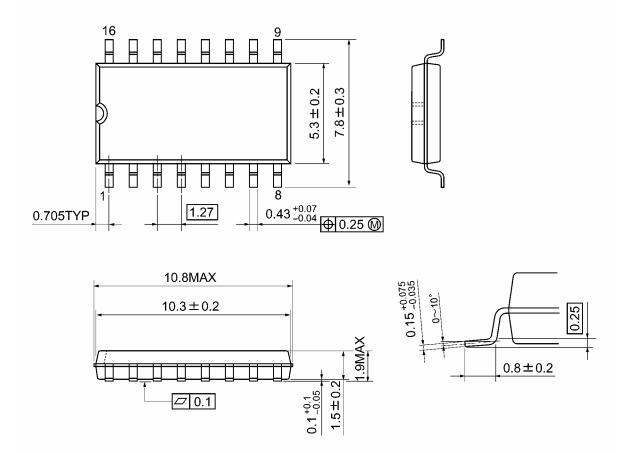
Package Dimensions



Weight: 1.00 g (typ.)

Package Dimensions

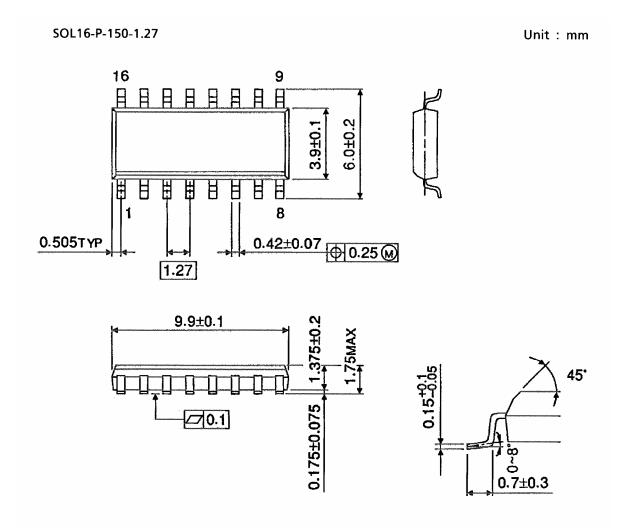
SOP16-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)



Package Dimensions (Note)



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Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

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20070701-EN GENERAL

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